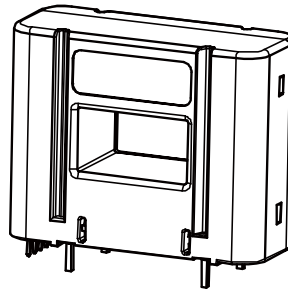


# CS1V P00 SERIES

## Current Sensor

### Model Number:

CS1V 80 P00  
 CS1V 100 P00  
 CS1V 150 P00  
 CS1V 200 P00



For the electronic measurement of current:DC,AC, pulsed..., with galvanic separation between the primary and the secondary circuits.

### Features

- ✧ Closed loop (compensated) current sensor using the Hall Effect
- ✧ Galvanic separation between primary and secondary
- ✧ Insulating plastic case recognized according to UL 94-V0
- ✧ Very good linearity
- ✧ High accuracy
- ✧ Very low offset drift over temperature
- ✧ No insertion loss
- ✧ Standards:
  - IEC 60664-1: 2020
  - IEC 61800-5-1: 2022
  - IEC 62109-1: 2010

### Applications

- ✧ AC variable speed and servo motor drives
- ✧ Uninterruptible Power Supplies (UPS)
- ✧ Battery management
- ✧ Switch Mode Power Supplies (SMPS)
- ✧ Power supplies for welding applications
- ✧ Inverter

## Safety

This sensor must be used according to IEC61800-5-1.

This sensor must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the following manufacture's operating instructions.

**Caution, risk of electrical shock!**



When operating the sensor, certain parts of the module can carry hazardous voltage (e.g., Primary busbar, power supply). Ignore this warning can lead to injury and/or cause serious damage.

This sensor is a built-in device, whose conducting parts must be inaccessible after installation. A protective housing or additional shield could be used.

Main supply must be able to be disconnected.

# CS1V P00 SERIES

## Absolute maximum ratings(not operating)

Parameter	Symbol	Unit	Value
Supply voltage	$V_C$	V	7
ESD rating, Human Body Model (HBM)	$V_{ESD}$	kV	4

- ✘ Stresses above these ratings may cause permanent damage.
- ✘ Exposure to absolute maximum ratings for extended periods may degrade reliability.

## Environmental and mechanical characteristics

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Ambient operating temperature	$T_A$	°C	-40		85	
Ambient storage temperature	$T_S$	°C	-55		125	
Mass	$m$	g		45		

## Insulation coordination

Parameter	Symbol	Unit	Value	Comment
Rms voltage for AC insulation test @ 50Hz, 1min	$V_d$	kV	3	According to IEC 60664-1
Impulse withstand voltage 1.2/50 $\mu$ s	$V_w$	kV	8	According to IEC 60664-1
Insulation resistance	$R_{IS}$	G $\Omega$	> 200	@500V, $T_A=25^\circ\text{C}$
Clearance (pri.-sec.)	$d_{cl}$	mm	12.9	
Creepage distance (pri.-sec.)	$d_{cp}$	mm	12.9	
Plastic case	-	-	UL94-V0	
Comparative tracking index	$CTI$		600	
Application example	-	-	600V	Reinforced insulation, according to IEC 61800-5-1, IEC 62109-1CAT III, PD2
Application example	-	-	1000V	Basic insulation, according to IEC 61800-5-1, IEC 62109-1CAT III, PD2

# CS1V P00 SERIES

## Electrical data

### CS1V 80 P00

※ With  $T_A = 25^\circ\text{C}$ ,  $V_C = 5\text{V}$ ,  $R_L = 10\Omega$ , unless otherwise noted.

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal rms current	$I_{PN}$	A		80		
Primary current, measuring range	$I_{PM}$	A		270		
Supply voltage	$V_C$	V	4.75	5	5.25	@ $\pm 5\%$
Current consumption	$I_C$	mA		$18 + I_P(\text{mA}) / N_S$	$20 + I_P(\text{mA}) / N_S$	@ $N_S = 2026$
Reference voltage	$V_{REF}$	V	2.485	2.5	2.515	@ $I_P = 0\text{A}$
Output voltage	$V_{OUT}$	V	0.25		4.75	@ $V_C = 5\text{V}$
Offset voltage	$V_{OUT}$	V		$V_{REF}$		
Electrical offset voltage	$V_{OE}$	mV	-2.8		2.8	
Electrical offset cur	$I_{OE}$	mA	-448		448	
Temperature coefficient of $I_{OE}$	$TCI_{OE}$	A/K	-0.002		0.002	
Temperature coefficient of $V_{REF}$	$TCV_{REF}$	ppm/K	-100		100	
Temperature coefficient of $V_{OE}$	$TCV_{OUT}$	ppm/K	-3		3	@ ppm/K of 2.5V
Theoretical sensitivity	$G_{th}$	mV/A		7.813		
Sensitivity error	$G$	%	-0.8		0.8	
Temperature drift of G	$TCG$	ppm/K			75	@ ppm/k of $I_{PN}$
Linearity error	$\epsilon_L$	% of $I_{PN}$	-0.1		0.1	
Magnetic offset current@ $10 \times I_P$	$I_{OM}$	mA	-83		83	
Output noise	$V_{no}$	mVpp		0.3 0.5		@ DC~10kHz @ DC~100kHz
Primary current, detection threshold	$I_{PTH}$	A	$2.35^* I_{PN}$	$2.41^* I_{PN}$	$2.47^* I_{PN}$	
Delay time of threshold output for high value	$t_{DH\ TH}$	$\mu\text{s}$		1.4	2.2	
Response time@ 10% of $I_{PN}$	$t_r$	$\mu\text{s}$			1	@ $di/dt = 50\text{A/s}$
Response time@ 80% of $I_{PN}$	$t_r$	$\mu\text{s}$			3	@ $di/dt = 50\text{A/s}$
Frequency bandwidth( $\pm 3\text{dB}$ )	$BW$	kHz	200			
Accuracy	$X$	% of $I_{PN}$			1	@ Notes 1)
Accuracy@ $85^\circ\text{C}$	$X$	% of $I_{PN}$			1.4	@ Notes 1)
Sum of sensitivity and and linearity	$\epsilon_{GL}$	% of $I_{PN}$			0.83	@ Notes 2)
Sum of sensitivity and and linearity@ $85^\circ\text{C}$	$\epsilon_{GL}$	% of $I_{PN}$			1.2	@ Notes 2)

Notes:

$$1) \quad X(T_A) = X_{25} + \left( TCG + \frac{TCI_{OE}}{I_{PN}} \right) X | T_A - 25 |$$

$$2) \quad \epsilon_{GL}(T_A) = \epsilon_{GL\ 25} + \left( TCG + \frac{TCI_{OE}}{I_{PN}} \right) X | T_A - 25 |$$

# CS1V P00 SERIES

## Electrical data

### CS1V 100 P00

※ With  $T_A = 25^\circ\text{C}$ ,  $V_C = 5\text{V}$ ,  $R_L = 10\Omega$ , unless otherwise noted.

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal rms current	$I_{PN}$	A		100		
Primary current, measuring range	$I_{PM}$	A		270		
Supply voltage	$V_C$	V	4.75	5	5.25	@ $\pm 5\%$
Current consumption	$I_C$	mA		$18 + I_P(\text{mA}) / N_S$	$20 + I_P(\text{mA}) / N_S$	@ $N_S = 2026$
Reference voltage	$V_{REF}$	V	2.485	2.5	2.515	@ $I_P = 0\text{A}$
Output voltage	$V_{OUT}$	V	0.25		4.75	@ $V_C = 5\text{V}$
Offset voltage	$V_{OUT}$	V		$V_{REF}$		
Electrical offset voltage	$V_{OE}$	mV	-2.8		2.8	
Electrical offset cur	$I_{OE}$	mA	-448		448	
Temperature coefficient of $I_{OE}$	$TCI_{OE}$	A/K	-0.002		0.002	
Temperature coefficient of $V_{REF}$	$TCV_{REF}$	ppm/K	-100		100	
Temperature coefficient of $V_{OE}$	$TCV_{OUT}$	ppm/K	-3		3	@ ppm/K of 2.5V
Theoretical sensitivity	$G_{th}$	mV/A		6.250		
Sensitivity error	$G$	%	-0.8		0.8	
Temperature drift of G	$TCG$	ppm/K			75	@ ppm/k of $I_{PN}$
Linearity error	$\varepsilon_L$	% of $I_{PN}$	-0.1		0.1	
Magnetic offset current@ $10 \times I_P$	$I_{OM}$	mA	-104		104	
Output noise	$V_{no}$	mVpp		5 6		@ DC~10kHz @ DC~100kHz
Primary current, detection threshold	$I_{PTH}$	A	$1.87^* I_{PN}$	$1.93^* I_{PN}$	$1.98^* I_{PN}$	
Delay time of threshold output for high value	$t_{DH\ TH}$	$\mu\text{s}$		1.4	2.2	
Response time@ 10% of $I_{PN}$	$t_r$	$\mu\text{s}$			1	@ $di/dt = 50\text{A/s}$
Response time@ 80% of $I_{PN}$	$t_r$	$\mu\text{s}$			3	@ $di/dt = 50\text{A/s}$
Frequency bandwidth( $\pm 3\text{dB}$ )	$BW$	kHz	200			
Accuracy	$X$	% of $I_{PN}$			1	@ Notes 1)
Accuracy@ $85^\circ\text{C}$	$X$	% of $I_{PN}$			1.4	@ Notes 1)
Sum of sensitivity and and linearity	$\varepsilon_{GL}$	% of $I_{PN}$			0.83	@ Notes 2)
Sum of sensitivity and and linearity@ $85^\circ\text{C}$	$\varepsilon_{GL}$	% of $I_{PN}$			1.2	@ Notes 2)

Notes:

$$1) X(T_A) = X_{25} + \left( TCG + \frac{TCI_{OE}}{I_{PN}} \right) X | T_A - 25 |$$

$$2) \varepsilon_{GL}(T_A) = \varepsilon_{GL\ 25} + \left( TCG + \frac{TCI_{OE}}{I_{PN}} \right) X | T_A - 25 |$$

# CS1V P00 SERIES

## Electrical data

### CS1V 150 P00

※ With  $T_A = 25^\circ\text{C}$ ,  $V_C = 5\text{V}$ ,  $R_L = 10\Omega$ , unless otherwise noted.

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal rms current	$I_{PN}$	A		150		
Primary current, measuring range	$I_{PM}$	A		270		
Supply voltage	$V_C$	V	4.75	5	5.25	@ $\pm 5\%$
Current consumption	$I_C$	mA		$18 + I_P(\text{mA}) / N_S$	$20 + I_P(\text{mA}) / N_S$	@ $N_S = 2026$
Reference voltage	$V_{REF}$	V	2.485	2.5	2.515	@ $I_P = 0\text{A}$
Output voltage	$V_{OUT}$	V	0.25		4.75	@ $V_C = 5\text{V}$
Offset voltage	$V_{OUT}$	V		$V_{REF}$		
Electrical offset voltage	$V_{OE}$	mV	-2.5		2.5	
Electrical offset cur	$I_{OE}$	mA	-600		600	
Temperature coefficient of $I_{OE}$	$TCI_{OE}$	A/K	-0.002		0.002	
Temperature coefficient of $V_{REF}$	$TCV_{REF}$	ppm/K	-100		100	
Temperature coefficient of $V_{OE}$	$TCV_{OUT}$	ppm/K	-3		3	@ ppm/K of 2.5V
Theoretical sensitivity	$G_{th}$	mV/A		4.167		
Sensitivity error	$G$	%	-0.8		0.8	
Temperature drift of G	$TCG$	ppm/K			75	@ ppm/k of $I_{PN}$
Linearity error	$\epsilon_L$	% of $I_{PN}$	-0.1		0.1	
Magnetic offset current@ $10 \times I_P$	$I_{OM}$	mA	-156		156	
Output noise	$V_{no}$	mVpp		5 6		@ DC~10kHz @ DC~100kHz
Primary current, detection threshold	$I_{PTH}$	A	$1.39^* / I_{PN}$	$1.44^* / I_{PN}$	$1.5^* / I_{PN}$	
Delay time of threshold output for high value	$t_{DH\ TH}$	$\mu\text{s}$		1.4	2.2	
Response time@ 10% of $I_{PN}$	$t_r$	$\mu\text{s}$			1	@ $di/dt = 50\text{A/s}$
Response time@ 80% of $I_{PN}$	$t_r$	$\mu\text{s}$			3	@ $di/dt = 50\text{A/s}$
Frequency bandwidth( $\pm 3\text{dB}$ )	$BW$	kHz	200			
Accuracy	$X$	% of $I_{PN}$			1	@ Notes 1)
Accuracy@ $85^\circ\text{C}$	$X$	% of $I_{PN}$			1.4	@ Notes 1)
Sum of sensitivity and and linearity	$\epsilon_{GL}$	% of $I_{PN}$			0.83	@ Notes 2)
Sum of sensitivity and and linearity@ $85^\circ\text{C}$	$\epsilon_{GL}$	% of $I_{PN}$			1.2	@ Notes 2)

Notes:

$$1) \quad X(T_A) = X_{25} + \left( TCG + \frac{TCI_{OE}}{I_{PN}} \right) \times |T_A - 25|$$

$$2) \quad \epsilon_{GL}(T_A) = \epsilon_{GL\ 25} + \left( TCG + \frac{TCI_{OE}}{I_{PN}} \right) \times |T_A - 25|$$

# CS1V P00 SERIES

## Electrical data

### CS1V 200 P00

※ With  $T_A = 25^\circ\text{C}$ ,  $V_C = 5\text{V}$ ,  $R_L = 10\Omega$ , unless otherwise noted.

Parameter	Symbol	Unit	Min	Typ	Max	Comment
Primary nominal rms current	$I_{PN}$	A		200		
Primary current, measuring range	$I_{PM}$	A	-450		450	
Supply voltage	$V_C$	V	4.75	5	5.25	@ $\pm 5\%$
Current consumption	$I_C$	mA		$18 + I_P(\text{mA}) / N_S$	$20 + I_P(\text{mA}) / N_S$	@ $N_S = 1500$
Reference voltage	$V_{REF}$	V	2.485	2.5	2.515	@ $I_P = 0\text{A}$
Output voltage	$V_{OUT}$	V	0.25		4.75	@ $V_C = 5\text{V}$
Offset voltage	$V_{OUT}$	V		$V_{REF}$		
Electrical offset voltage	$V_{OE}$	mV	-2.5		2.5	
Electrical offset cur	$I_{OE}$	mA	-800		800	
Temperature coefficient of $I_{OE}$	$TCI_{OE}$	A/K	-0.002		0.002	
Temperature coefficient of $V_{REF}$	$TCV_{REF}$	ppm/K			$\pm 100$	
Temperature coefficient of $V_{OE}$	$TCV_{OUT}$	ppm/K			$\pm 2$	@ ppm/K of 2.5V
Theoretical sensitivity	$G_{th}$	mV/A		3.125		
Sensitivity error	$G$	%	-0.8		0.8	
Temperature drift of G	$TCG$	ppm/K			75	@ ppm/k of $I_{PN}$
Linearity error	$\varepsilon_L$	% of $I_{PN}$	-0.15		0.15	
Magnetic offset current@ $10 \times I_P$	$I_{OM}$	mA	-208		208	
Output noise	$V_{no}$	mVpp		5 6		@ DC~10kHz @ DC~100kHz
Primary current, detection threshold	$I_{PTH}$	A	$1.87^* I_{PN}$	$1.93^* I_{PN}$	$1.98^* I_{PN}$	
Delay time of threshold output for high value	$t_{DH\ TH}$	$\mu\text{s}$		1.4	2.2	
Response time@ 10% of $I_{PN}$	$t_r$	$\mu\text{s}$			1	@ $di/dt = 70\text{A/s}$
Response time@ 80% of $I_{PN}$	$t_r$	$\mu\text{s}$			3	@ $di/dt = 70\text{A/s}$
Frequency bandwidth( $\pm 3\text{dB}$ )	$BW$	kHz	200			
Accuracy	$X$	% of $I_{PN}$			1.1	@ Notes 1)
Accuracy@ $85^\circ\text{C}$	$X$	% of $I_{PN}$			1.4	@ Notes 1)
Sum of sensitivity and and linearity	$\varepsilon_{GL}$	% of $I_{PN}$			0.83	@ Notes 2)
Sum of sensitivity and and linearity@ $85^\circ\text{C}$	$\varepsilon_{GL}$	% of $I_{PN}$			1.2	@ Notes 2)

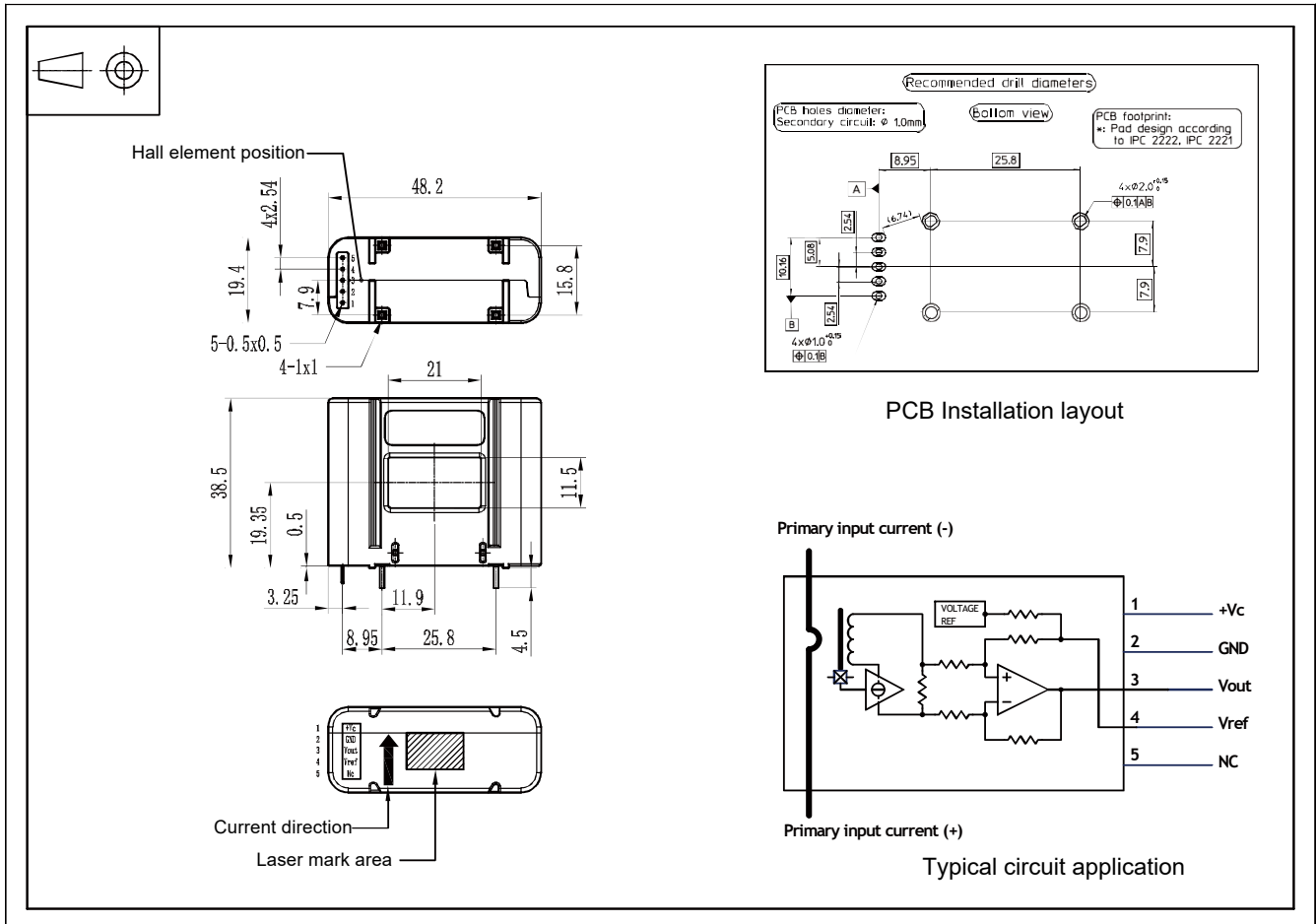
Notes:

$$1) X(T_A) = X_{25} + \left( TCG + \frac{TCI_{OE}}{I_{PN}} \right) X | T_A - 25 |$$

$$2) \varepsilon_{GL}(T_A) = \varepsilon_{GL\ 25} + \left( TCG + \frac{TCI_{OE}}{I_{PN}} \right) X | T_A - 25 |$$

# CS1V P00 SERIES

Dimensions (in mm. 1 mm = 0.0394 inch)



## Mechanical characteristics

◇ General tolerance  $\pm 0.6$  mm

## Remarks

This is a series of standard models, for different versions (supply voltages, connectors...), please contact CHIPSENSE.